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Supplementary Information

Exposure to Solvent Vapours for Enhanced N-type OTFT Stability

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Figure S1: GIWAXS scattering patterns of P(NDI2OD-T2). (a) Baseline, (b) Aniline-exposed, (c) Pyridine-exposed



Figure S2: Linecuts of GIWAXS in-plane scattering between $0.01 \le q_z \le 0.2$.



Figure S3: Stability of P(NDI2OD-T2) devices over one week. a) Device electron mobility. b) Device threshold voltage.